



Sample &

Buv







TS5A23159

SCDS201H-AUGUST 2005-REVISED FEBRUARY 2015

TS5A23159 1-Ω 2-Channel SPDT Analog Switch 5-V / 3.3-V 2-Channel 2:1 Multiplexer / Demultiplexer

Features 1

- Isolation in Power-Down Mode, $V_{CC} = 0$
- Specified Break-Before-Make Switching
- Low ON-State Resistance (1 Ω)
- Control Inputs are 5.5-V Tolerant
- Low Charge Injection
- **Excellent ON-State Resistance Matching**
- Low Total Harmonic Distortion (THD)
- Supports Analog and Digital Signals
- 1.65-V to 5.5-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

Applications 2

- **Cell Phones**
- **PDAs**
- Portable Instrumentation
- Audio and Video Signal Routing
- Low-Voltage Data-Acquisition Systems
- **Communication Circuits**
- Modems
- Hard Drives
- **Computer Peripherals**
- Wireless Terminals and Peripherals

3 Description

The TS5A23159 is a bidirectional 2-channel singlepole double-throw (SPDT) switch that is designed to operate from 1.65 V to 5.5 V. The device offers low ON-state resistance and excellent **ON-state** resistance matching with the break-before-make feature which prevents signal distortion during the transferring of a signal from one channel to another. The device has an excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for a wide variety of portable applications including cell phones, audio devices, and instrumentation.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) | | |
|-------------|------------|-------------------|--|--|
| TS5A23159 | VSSOP (10) | 3.00 mm × 3.00 mm | | |
| | UQFN (10) | 1.50 mm × 2.00 mm | | |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

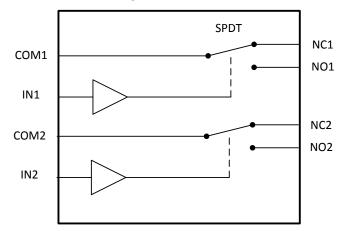




Table of Contents

| 1 | Feat | ures 1 |
|---|------|--|
| 2 | Арр | lications 1 |
| 3 | | cription 1 |
| 4 | Rev | ision History 2 |
| 5 | Pin | Configuration and Functions |
| 6 | Spe | cifications |
| | 6.1 | Absolute Maximum Ratings 3 |
| | 6.2 | ESD Ratings 4 |
| | 6.3 | Recommended Operating Conditions 4 |
| | 6.4 | Thermal Information 4 |
| | 6.5 | Electrical Characteristics for 5-V Supply 5 |
| | 6.6 | Electrical Characteristics for 3.3-V Supply 7 |
| | 6.7 | Electrical Characteristics for 2.5-V Supply 9 |
| | 6.8 | Electrical Characteristics for 1.8-V Supply 11 |
| | 6.9 | Typical Characteristics 13 |
| 7 | | ameter Measurement Information 16 |
| 8 | Deta | ailed Description |

| | 8.1 | Overview | 21 |
|----|------|-----------------------------------|----|
| | 8.2 | Functional Block Diagram | 21 |
| | 8.3 | Feature Description | 21 |
| | 8.4 | Device Functional Modes | 21 |
| 9 | App | lication and Implementation | 22 |
| | 9.1 | Application Information | 22 |
| | 9.2 | Typical Application | 22 |
| 10 | Pow | ver Supply Recommendations | 23 |
| 11 | Lay | out | 24 |
| | 11.1 | Layout Guidelines | 24 |
| | 11.2 | Layout Example | 24 |
| 12 | Dev | ice and Documentation Support | 25 |
| | 12.1 | Trademarks | 25 |
| | 12.2 | Electrostatic Discharge Caution | 25 |
| | 12.3 | Glossary | 25 |
| 13 | Mec | hanical, Packaging, and Orderable | |
| | Info | rmation | 25 |
| | | | |

Copyright © 2005–2015, Texas Instruments Incorporated

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (August 2013) to Revision H

| Aligner | d package description throughout datasheet | 1 |
|------------------|--|-----------------------------------|
| Changes f | from Revision F (September 2010) to Revision G | Page |
| Descrip Recom | ESD Ratings table, Recommended Operating Conditions table, Thermal Informa ption section, Device Functional Modes, Application and Implementation section, nmendations section, Layout section, Device and Documentation Support section, ging, and Orderable Information section | Power Supply , and Mechanical, |

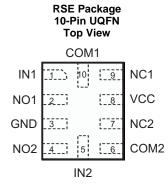
Removed Ordering Information table. 1

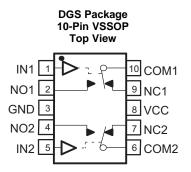
www.ti.com

Page



Pin Configuration and Functions 5





Pin Functions

| Р | IN | I/O | DESCRIPTION | |
|-----|------|-----|--|--|
| NO. | NAME | 1/0 | DESCRIPTION | |
| 1 | IN1 | I | Digital control to connect COM to NO or NC | |
| 2 | NO1 | I/O | Normally open | |
| 3 | GND | — | Ground | |
| 4 | NO2 | I/O | Normally open | |
| 5 | IN2 | I | Digital control to connect COM to NO or NC | |
| 6 | COM2 | I/O | Common | |
| 7 | NC2 | I/O | Normally closed | |
| 8 | VCC | — | Power supply | |
| 9 | NC1 | I/O | Normally closed | |
| 10 | COM1 | I/O | Common | |

Specifications 6

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾⁽²⁾

| | | | MIN | MAX | UNIT |
|--|---|---|------|-----------------------|------|
| V _{CC} | Supply voltage ⁽³⁾ | | -0.5 | 6.5 | V |
| V _{NC} V _{NO} V _{COM} | Analog voltage ⁽³⁾ (4) (5) | | -0.5 | V _{CC} + 0.5 | V |
| Ι _Κ | Analog port diode current | $V_{NC}, V_{NO}, V_{COM} < 0$ | -50 | | mA |
| I _{NC} | On-state switch current | | -200 | 200 | |
| I _{NO} I _{COM} | On-state peak switch current ⁽⁶⁾ | $V_{\rm NC}$, $V_{\rm NO}$, $V_{\rm COM}$ = 0 to $V_{\rm CC}$ | -400 | 400 | mA |
| V _{IN} | Digital input voltage ⁽³⁾ ⁽⁴⁾ | | -0.5 | 6.5 | V |
| I _{IK} | Digital input clamp current | V ₁ < 0 | -50 | | mA |
| I _{CC} | Continuous current through V _{CC} | | | 100 | mA |
| I _{GND} | Continuous current through GND | | -100 | 100 | mA |
| T _{stg} | Storage temperature | | -65 | 150 | °C |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. (2)

The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

All voltages are with respect to ground, unless otherwise specified. (3)

(4)The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(5) This value is limited to 5.5 V maximum.

Pulse at 1-ms duration < 10% duty cycle (6)

Copyright © 2005-2015, Texas Instruments Incorporated

SCDS201H-AUGUST 2005-REVISED FEBRUARY 2015

STRUMENTS www.ti.com

EXAS

6.2 ESD Ratings

| | | | VALUE | UNIT |
|-------------|-------------------------|--|-------|------|
| | | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | |
| $V_{(ESD)}$ | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 $^{\rm (2)}$ | ±1000 | V |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|--|-----------------------------|-----|-----------------|------|
| V _{CC} | Supply LC Voltage | 0 | 5.5 | |
| V _{NC} V _{NO} V _{COM} | Analog voltage | 0 | V _{CC} | V |
| V _{IN} | Digital input voltage range | 0 | V _{CC} | |

6.4 Thermal Information

| | | TS5A | | |
|-----------------------|--|-------------|------------|------|
| | THERMAL METRIC ⁽¹⁾ | DGS (VSSOP) | RSE (UQFN) | UNIT |
| | | 10 PINS | 10 PINS | |
| $R_{	extsf{	heta}JA}$ | Junction-to-ambient thermal resistance | 203.9 | 180.8 | |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 88.3 | 117.8 | |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 123.9 | 98.6 | °C/W |
| ΨJT | Junction-to-top characterization parameter | 2.1 | 6.8 | C/ W |
| ψ_{JB} | Junction-to-board characterization parameter | 122.5 | 98.4 | |
| R _{0JC(bot)} | Junction-to-case (bottom) thermal resistance | — | | |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

6.5 Electrical Characteristics for 5-V Supply

 V_{CC} = 4.5 V to 5.5 V, T_{A} = –40°C to 85°C (unless otherwise noted) $^{(1)}$

| | PARAMETER | TEST CONDI | TIONS | TA | V _{cc} | MIN | TYP | MAX | UNIT |
|--|---|--|--|--------------|----------------------|------------|------|-----------------|------|
| ANALOG SW | ІТСН | | | | | | | | |
| V _{COM} V _{NO} V _{NC} | Analog signal range | | | | | 0 | | V _{CC} | V |
| R _{peak} | Peak ON resistance | $\label{eq:VNC} \begin{array}{l} 0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{CC}, \\ I_{COM} = -100 \text{ mA}, \end{array}$ | Switch ON, See Figure 14 | 25°C Full | 4.5 V | | 0.8 | 1.1 1.5 | Ω |
| R _{on} | ON-state resistance | V_{NO} or $V_{NC} = 2.5 V$, $I_{COM} = -100 \text{ mA}$, | Switch ON, See Figure 14 | 25°C Full | 4.5 V | | 0.7 | 0.9 1.1 | Ω |
| | ON-state | | 0 | 25°C | | | 0.05 | 0.1 | |
| ΔR_{on} | resistance match between channels | V_{NO} or V_{NC} = 2.5 V, I_{COM} = -100 mA, | Switch ON, See Figure 14 | Full | 4.5 V | | | 0.1 | Ω |
| | | $\label{eq:VNC} \begin{array}{l} 0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{CC}, \\ I_{COM} = -100 \text{ mA}, \end{array}$ | Switch ON, See Figure 14 | 25°C | | | 0.15 | | |
| R _{on(flat)} | ON-state resistance | $V_{\rm NO}$ or $V_{\rm NC}$ = 1 V, 1.5 | | 25°C | 4.5 V | | 0.1 | 0.25 | Ω |
| | flatness | V, 2.5 V, I _{COM} = -100 mA, | Switch ON, See Figure 14 | Full | | | | 0.25 | |
| | | V_{NC} or $V_{NO} = 1 V$, | | 25°C | | -20 | 2 | 20 | |
| I _{NO(OFF)} , I _{NC(OFF)} | NC, NO OFF leakage current | $\label{eq:V_COM} \begin{array}{l} V_{COM} = 1 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$ | Switch OFF, See Figure 15 | Full | 5.5 V | -100 | | 100 | nA |
| | | $V_{\rm NC}$ or $V_{\rm NO}$ = 0 to 5.5 | Switch OFF, See Figure 15 | 25°C | | -1 | 0.2 | 1 | μA |
| I _{NC(PWROFF)} , I _{NO(PWROFF)} | | V | | Full | 0 V | -20 | | 20 | |
| | NC, NO ON leakage current | V_{NC} or $V_{NO} = 1 V$, | | 25°C | - | -20 | 2 | 20 | 1 |
| I _{NO(ON)} , I _{NC(ON)} | | $\label{eq:V_COM} \begin{array}{l} V_{COM} = Open, \\ or \\ V_{NC} \; or \; V_{NO} = 4.5 \; V, \\ V_{COM} = Open, \end{array}$ | Switch ON, See Figure 16 | Full | 5.5 V | -100 | | 100 | nA |
| | COM | $V_{\rm NC}$ or $V_{\rm NO} = 0$ to 5.5 | Switch OFF, | 25°C | | -1 | 0.1 | 1 | |
| COM(PWROFF) | OFF leakage current | V, V _{COM} = 5.5 V to 0, | See Figure 15 | Full | 0 V | -20 | | 20 | μA |
| | 2011 | V_{NC} or V_{NO} = Open, | | 25°C | | -20 | 2 | 20 | |
| I _{COM(ON)} | COM ON leakage current | $ \begin{array}{l} V_{COM} = 1 \ V, \\ or \\ V_{NC} \ or \ V_{NO} = Open, \\ V_{COM} = 4.5 \ V, \end{array} $ | Switch ON, See Figure 16 | Full | 5.5 V | -100 | | 100 | nA |
| DIGITAL CON | ITROL INPUTS (IN1, IN2) ⁽²⁾ | | | | | | | | |
| V _{IH} | Input logic high | | | Full | | 2.4 | | 5.5 | V |
| V _{IL} | Input logic low | | | Full | | 0 | | 0.8 | V |
| I _{IH} , I _{IL} | Input leakage current | $V_{IN} = 5.5 V \text{ or } 0$ | | 25°C Full | 5.5 V | -2 -100 | | 2 100 | nA |
| DYNAMIC | | | | | | | | | |
| | | | 0 05 - | 25°C | 5 V | 1 | 8 | 13 | |
| t _{ON} | Turnon time | | C _L = 35 pF, See Figure 18 | Full | 4.5 V to 5.5 V | 1 | | 16.5 | ns |
| | | | | 25°C | 5 V | 1 | 5 | 8 | |
| t _{OFF} | Turnoff time | | C _L = 35 pF, See Figure 18 | Full | 4.5 V to 5.5 V | 1 | | 8 | ns |

The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
 All unused digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, SCBA004.

TEXAS INSTRUMENTS

www.ti.com

Electrical Characteristics for 5-V Supply (continued)

 V_{CC} = 4.5 V to 5.5 V, T_{A} = –40°C to 85°C (unless otherwise noted)^{(1)}

| | PARAMETER | TEST COND | ITIONS | TA | Vcc | MIN 1 | MIN TYP | MAX | UNIT |
|--|---------------------------------|---|--|------|--------------|-------|---------|-----|------|
| | | $V_{NC} = V_{NO} = V_{CC}$ | C _I = 35 pF, | 25°C | 5 V 4.5 V | 1 | 5.5 | 13 | |
| t _{BBM} | Break-before-make time | $R_L = 50 \Omega,$ | See Figure 19 | Full | to 5.5 V | 1 | | 14 | ns |
| Q _C | Charge injection | $V_{GEN} = 0,$ R _{GEN} = 0, | C _L = 1 nF, See Figure 23 | 25°C | 5 V | | -7 | | рС |
| $C_{NC(OFF)}, C_{NO(OFF)}$ | NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_{CC}$ or GND, Switch OFF, | See Figure 17 | 25°C | 5 V | | 18 | | pF |
| C _{NC(ON)} , C _{NO(ON)} | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_{CC}$ or GND, Switch ON, | See Figure 17 | 25°C | 5 V | | 55 | | pF |
| C _{COM(ON)} | COM ON capacitance | $V_{COM} = V_{CC}$ or GND, Switch ON, | See Figure 17 | 25°C | 5 V | Ę | 54.5 | | pF |
| CI | Digital input capacitance | $V_{IN} = V_{CC}$ or GND, | See Figure 17 | 25°C | 5 V | | 2 | | pF |
| BW | Bandwidth | $R_L = 50 \Omega$, Switch ON, | See Figure 20 | 25°C | 5 V | | 100 | | MHz |
| O _{ISO} | OFF isolation | $\begin{array}{l} R_{L} = 50 \ \Omega, \\ f = 1 \ MHz, \end{array}$ | Switch OFF, See Figure 21 | 25°C | 5 V | | -64 | | dB |
| X _{TALK} | Crosstalk | $\begin{array}{l} R_{L} = 50 \ \Omega, \\ f = 1 \ MHz, \end{array}$ | Switch ON, See Figure 22 | 25°C | 5 V | | -64 | | dB |
| THD | Total harmonic distortion | $\begin{aligned} R_L &= 600 \ \Omega, \\ C_L &= 50 \ pF, \end{aligned}$ | f = 20 Hz to 20 kHz, See Figure 24 | 25°C | 5 V | 0.00 |)4% | | |
| SUPPLY | | | | | | | | | |
| | Positive | | Switch ON or | 25°C | | | 10 | 50 | |
| I _{CC} | supply current | $V_{IN} = V_{CC}$ or GND, | OFF | Full | 5.5 V | | | 750 | nA |

6.6 Electrical Characteristics for 3.3-V Supply

 V_{CC} = 3 V to 3.6 V, T_A = –40°C to 85°C (unless otherwise noted) $^{(1)}$

| PAR | AMETER | TEST CON | DITIONS | T _A | V _{cc} | MIN | TYP | MAX | UNIT |
|---|--|---|--|----------------|-----------------|-----|------|------------|------------|
| ANALOG SWI | тсн | | | | •• | | | | |
| V _{COM} , V _{NO} , V _{NC} | Analog signal range | | | | | 0 | | V_{CC} | V |
| R _{peak} | Peak ON resistance | $\begin{array}{l} 0 \leq (V_{\text{NO}} \text{ or } V_{\text{NC}}) \leq V_{\text{CC}}, \\ I_{\text{COM}} = -100 \text{ mA}, \end{array}$ | Switch ON, See Figure 14 | 25°C Full | 3 V | | 1.3 | 1.6 2 | Ω |
| R _{on} | ON-state resistance | V_{NO} or $V_{NC} = 2 V$, $I_{COM} = -100 \text{ mA}$, | Switch ON, See Figure 14 | 25°C Full | 3 V | | 1.2 | 1.5 1.7 | Ω |
| | ON-state | | | 25°C | | | 0.1 | 0.15 | |
| ΔR _{on} | resistance match between channels | V_{NO} or V_{NC} = 2 V, 0.8 V, I_{COM} = -100 mA, | Switch ON, See Figure 14 | Full | 3 V | | 0.2 | | Ω |
| _ | ON-state | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_{CC},$ $I_{COM} = -100 \text{ mA},$ | Switch ON, See Figure 14 | 25°C | | | 0.15 | | _ |
| R _{on(flat)} | resistance flatness | V _{NO} or V _{NC} = 2 V, 0.8 V, | Switch ON, | 25°C | 3 V | | | | Ω |
| | | $I_{COM} = -100 \text{ mA},$ | See Figure 14 | Full | | | | | |
| | | V_{NC} or $V_{NO} = 1 V$, | | 25°C |] | -20 | 2 | 20 | |
| I _{NO(OFF)} , I _{NC(OFF)} | NC, NO OFF leakage _ current | $\label{eq:VCOM} \begin{array}{l} V_{COM} = 1 \ V \ to \ 3 \ V, \\ or \\ V_{NC} \ or \ V_{NO} = 3 \ V, \\ V_{COM} = 1 \ V \ to \ 3 \ V, \end{array}$ | Switch OFF, See Figure 15 | Full | 3.6 V | -50 | | 50 | nA |
| I _{NC(PWROFF)} , | current | V_{NC} or $V_{NO} = 0$ to 3.6 V, | Switch OFF, | 25°C | 0.14 | -1 | 0.2 | 1 | |
| I _{NO(PWROFF)} | | $V_{COM} = 3.6 V \text{ to } 0,$ | See Figure 15 | Full | 0 V | -15 | | 15 | μA |
| | V_{NC} or $V_{NO} = 1 V$, | | 25°C | | -10 | 2 | 10 | | |
| I _{NO(ON)} , I _{NC(ON)} | NC, NO ON leakage current | $\label{eq:com} \begin{array}{l} V_{COM} = Open, \\ or \\ V_{NC} \mbox{ or } V_{NO} = 3 \mbox{ V}, \\ V_{COM} = Open, \end{array}$ | Switch ON, See Figure 16 | Full | 3.6 V | -20 | | 20 | nA |
| | СОМ | | | 25°C | | -1 | 0.2 | 1 | |
| I _{COM} (PWROFF) | OFF leakage current | $\label{eq:VNC} \begin{array}{l} V_{\text{NC}} \text{ or } V_{\text{NO}} = 3.6 \text{ V to } 0, \\ V_{\text{COM}} = 0 \text{ to } 3.6 \text{ V}, \end{array}$ | Switch OFF, See Figure 15 | Full | 0 V | -15 | | 15 | μA |
| | 0014 | V_{NC} or V_{NO} = Open, | | 25°C | | -10 | 2 | 10 | |
| I _{COM(ON)} | COM ON leakage current | $\label{eq:VCOM} \begin{array}{l} V_{COM} = 1 \ V, \\ \text{or} \\ V_{NC} \ \text{or} \ V_{NO} = \text{Open}, \\ V_{COM} = 3 \ V, \end{array}$ | Switch ON, See Figure 16 | Full | 3.6 V | -20 | | 20 | nA |
| DIGITAL CON | TROL INPUTS (IN ⁻ | 1, IN2) ⁽²⁾ | | | | | | | |
| VIH | Input logic high | | | Full | | 2 | | 5.5 | V |
| V _{IL} | Input logic low | | | Full | | 0 | | 0.8 | V |
| | Input leakage | V = 5 E V or 0 | | 25°C | 261 | -2 | | 2 | n A |
| I _{IH} , I _{IL} | current | V _{IN} = 5.5 V or 0 | | Full | 3.6 V | -20 | | 20 | nA |
| DYNAMIC | | | | | | | | | |
| | | V . V | C _L = 35 pF, | 25°C | 3.3 V | 5 | 11 | 19 | |
| t _{ON} | Turnon time | | C _L = 35 pF, See Figure 18 | Full | 3 V to 3.6 V | 3 | | 22 | ns |
| | | $V_{COM} = V_{CC},$ | C _I = 35 pF, | 25°C | 3.3 V | 1 | 5 | 9 | |
| t _{OFF} | Turnoff time | $v_{COM} = v_{CC},$ $R_L = 50 \Omega,$ | C _L = 35 pF, See Figure 18 | Full | 3 V to 3.6 V | 1 | | 9 | ns |
| | Break-before- | $V_{NC} = V_{NO} = V_{CC},$ | C _L = 35 pF, | 25°C | 3.3 V | 1 | 7 | 17 | |
| t _{BBM} | make time | $v_{NC} = v_{NO} = v_{CC},$ $R_{L} = 50 \Omega,$ | $G_L = 35 \text{ pr},$ See Figure 19 | Full | 3 V to 3.6 V | 1 | | 20 | ns |

The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
 All unused digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, SCBA004.

NSTRUMENTS

EXAS

Electrical Characteristics for 3.3-V Supply (continued)

| $V_{CC} = 3 \text{ V}$ to 3.6 V, $T_A = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted) ⁽¹⁾ | 1) |
|--|----|
|--|----|

| PA | RAMETER | TEST COND | ITIONS | TA | V _{cc} | MIN TYP MAX | UNIT |
|---|------------------------------|--|--|------|-----------------|-------------|------|
| Q _C | Charge injection | V _{GEN} = 0, R _{GEN} = 0, | C _L = 1 nF, See Figure 23 | 25°C | 3.3 V | -4 | рС |
| $\begin{array}{c} C_{NC(OFF)},\\ C_{NO(OFF)} \end{array}$ | NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_{CC}$ or GND, Switch OFF, | See Figure 17 | 25°C | 3.3 V | 18 | pF |
| C _{NC(ON)} , C _{NO(ON)} | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_{CC}$ or GND, Switch ON, | See Figure 17 | 25°C | 3.3 V | 56 | pF |
| C _{COM(ON)} | COM ON capacitance | $V_{COM} = V_{CC}$ or GND, Switch ON, | See Figure 17 | 25°C | 3.3 V | 56 | pF |
| CI | Digital input capacitance | $V_{IN} = V_{CC}$ or GND, | See Figure 17 | 25°C | 3.3 V | 2 | pF |
| BW | Bandwidth | $R_L = 50 \Omega$, Switch ON, | See Figure 20 | 25°C | 3.3 V | 100 | MHz |
| O _{ISO} | OFF isolation | $R_{L} = 50 \ \Omega,$ f = 1 MHz, | Switch OFF, See Figure 21 | 25°C | 3.3 V | -64 | dB |
| X _{TALK} | Crosstalk | $R_{L} = 50 \ \Omega,$ f = 1 MHz, | Switch ON, See Figure 22 | 25°C | 3.3 V | -64 | dB |
| THD | Total harmonic distortion | | f = 20 Hz to 20 kHz, See Figure 24 | 25°C | 3.3 V | 0.01% | |
| SUPPLY | | | | | | | |
| 1 | Positive supply | V _{IN} = V _{CC} or GND, | Switch ON or OFF | 25°C | 3.6 V | 25 | nA |
| I _{CC} | current | VIN - VCC OF GIVD, | Switch ON OFF | Full | 3.0 V | 150 | |

6.7 Electrical Characteristics for 2.5-V Supply⁽¹⁾

 V_{CC} = 2.3 V to 2.7 V, T_A = -40°C to 85°C (unless otherwise noted)

| PAR | AMETER | TEST COND | ITIONS | TA | V _{cc} | MIN | TYP | MAX | UNIT |
|---|--|---|--|--------------|-------------------|-----|------|------------|------|
| ANALOG SWI | тсн | | | | | | | | |
| V _{COM} , V _{NO} , V _{NC} | Analog signal range | | | | | 0 | | V_{CC} | V |
| R _{peak} | Peak ON resistance | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_{CC},$ $I_{COM} = -8 \text{ mA},$ | Switch ON, See Figure 14 | 25°C Full | 2.3 V | | 1.8 | 2.5 2.7 | Ω |
| R _{on} | ON-state | V_{NO} or $V_{NC} = 1.8 V$, | Switch ON, | 25°C | 2.3 V | | 1.5 | 2 | Ω |
| | resistance | $I_{COM} = -8 \text{ mA},$ | See Figure 14 | Full | | | | 2.4 | |
| ΔR _{on} | ON-state resistance match between channels | $V_{\rm NO}$ or $V_{\rm NC}$ = 1.8 V, 0.8 V, $I_{\rm COM}$ = –8 mA, | Switch ON, See Figure 14 | 25°C Full | 2.3 V | | 0.15 | 0.2 | Ω |
| | ON-state | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_{CC},$ $I_{COM} = -8 \text{ mA},$ | Switch ON, See Figure 14 | 25°C | | | 0.6 | | |
| R _{on(flat)} | resistance flatness | $V_{NO} \text{ or } V_{NC} = 0.8 \text{ V}, 1.8 \text{ V},$ | Switch ON, | 25°C | 2.3 V | | 0.6 | 1 | Ω |
| | | $I_{COM} = -8 \text{ mA},$ | See Figure 14 | Full | | | | 1 | |
| | | V_{NC} or $V_{NO} = 0.5 V$, | | 25°C | | -20 | 2 | 20 | |
| I _{NO(OFF)} , I _{NC(OFF)} | NC, NO OFF leakage current | | Switch OFF, See Figure 15 | Full | 2.3 V | -50 | | 50 | nA |
| I _{NC(PWROFF)} , | | V_{NC} or $V_{NO} = 0$ to 2.7 V, | Switch OFF, | 25°C | 0.1/ | -1 | 0.1 | 1.0 | |
| I _{NO(PWROFF)} | | $V_{COM} = 2.7 V \text{ to } 0,$ | See Figure 15 | Full | 0 V | -10 | | 10 | μA |
| | | V_{NC} or $V_{NO} = 0.5$ V, | | 25°C | | -10 | 2 | 10 | |
| I _{NO(ON)} , I _{NC(ON)} | NC, NO ON leakage current | $\label{eq:com} \begin{array}{l} V_{COM} = \text{Open}, \\ \text{or} \\ V_{NC} \text{ or } V_{NO} = 2.2 \text{ V}, \\ V_{COM} = \text{Open}, \end{array}$ | Switch ON, See Figure 16 | Full | 2.7 V | -20 | | 20 | nA |
| | COM | V_{NC} or $V_{NO} = 2.7$ V to 0, | Switch OFF, | 25°C | | -1 | 0.1 | 1 | |
| I _{COM(PWROFF)} | OFF leakage current | $V_{\rm NC}$ of $V_{\rm NO} = 2.7$ V to 0, $V_{\rm COM} = 0$ to 2.7 V, | See Figure 15 | Full | 0 V | -10 | | 10 | μA |
| | | V_{NC} or V_{NO} = Open, | | 25°C | _ | -10 | 2 | 10 | nA |
| I _{COM(ON)} | COM ON leakage current | $\label{eq:VCOM} \begin{array}{l} V_{COM} = 0.5 \ V, \\ \text{or} \\ V_{NC} \ \text{or} \ V_{NO} = \text{Open}, \\ V_{COM} = 2.2 \ V, \end{array}$ | Switch ON, See Figure 16 | Full | 2.7 V | -20 | | 20 | |
| DIGITAL CON | TROL INPUTS (IN | 1, IN2) ⁽²⁾ | | | | | | | |
| V _{IH} | Input logic high | | | Full | | 1.8 | | 5.5 | V |
| V _{IL} | Input logic low | | | Full | | 0 | | 0.6 | V |
| | Input leakage | | | 25°C | 271 | -2 | | 2 | n۸ |
| I _{IH} , I _{IL} | current | $V_{IN} = 5.5 V \text{ or } 0$ | | Full | 2.7 V | -20 | | 20 | nA |
| DYNAMIC | | | | | | | | | |
| | | | 0 25 -5 | 25°C | 2.5 V | 5 | 15 | 28 | |
| t _{ON} | Turnon time | $V_{\rm COM} = V_{\rm CC}, \\ R_{\rm L} = 50 \ \Omega, \label{eq:com}$ | C _L = 35 pF, See Figure 18 | Full | 2.3 V to 2.7 V | 5 | | 32 | ns |
| | | | C 35 ~E | 25°C | 2.5 V | 2 | 6 | 9 | |
| t _{OFF} | Turnoff time | $V_{COM} = V_{CC},$ R _L = 50 Ω, | C _L = 35 pF, See Figure 18 | Full | 2.3 V to 2.7 V | 2 | | 10 | ns |
| | Drook kafara | | 0 25 -5 | 25°C | 2.5 V | 1 | 10 | 27 | 7 |
| t _{BBM} | Break-before- make time | | C _L = 35 pF, See Figure 19 | Full | 2.3 V to 2.7 V | 1 | | 30 | ns |

The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
 All unused digital inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, SCBA004.

Electrical Characteristics for 2.5-V Supply⁽¹⁾ (continued)

| PA | RAMETER | TEST COND | ITIONS | TA | V _{cc} | MIN TYP | MAX | UNIT |
|---|------------------------------|---|--|------|-----------------|---------|-----|------|
| Q _C | Charge injection | V _{GEN} = 0, R _{GEN} = 0, | C _L = 1 nF, See Figure 23 | 25°C | 2.5 V | -3 | | рС |
| $\begin{array}{c} C_{NC(OFF)},\\ C_{NO(OFF)} \end{array}$ | NC, NO OFF capacitance | V_{NC} or V_{NO} = V_{CC} or GND, Switch OFF, | See Figure 17 | 25°C | 2.5 V | 18.5 | | pF |
| C _{NC(ON)} , C _{NO(ON)} | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_{CC}$ or GND, Switch ON, | See Figure 17 | 25°C | 2.5 V | 56.5 | | pF |
| C _{COM(ON)} | COM ON capacitance | $V_{COM} = V_{CC}$ or GND, Switch ON, | See Figure 17 | 25°C | 2.5 V | 56.5 | | pF |
| CI | Digital input capacitance | $V_{IN} = V_{CC}$ or GND, | See Figure 17 | 25°C | 2.5 V | 2 | | pF |
| BW | Bandwidth | $R_L = 50 \Omega$, Switch ON, | See Figure 20 | 25°C | 2.5 V | 100 | | MHz |
| O _{ISO} | OFF isolation | $R_{L} = 50 \ \Omega,$ f = 1 MHz, | Switch OFF, See Figure 21 | 25°C | 2.5 V | -64 | | dB |
| X _{TALK} | Crosstalk | $ \begin{array}{l} R_L = 50 \ \Omega, \\ f = 1 \ MHz, \end{array} $ | Switch ON, See Figure 22 | 25°C | 2.5 V | -64 | | dB |
| THD | Total harmonic distortion | | f = 20 Hz to 20 kHz, See Figure 24 | 25°C | 2.5 V | 0.02% | | |
| SUPPLY | | | | | | | | |
| 1 | Positive supply | | Switch ON or OFF | 25°C | 2.7 V | 10 | 25 | nA |
| I _{CC} | current | $V_{IN} = V_{CC}$ or GND, | Switch ON OF | Full | 2.7 V | | 100 | ΠA |



6.8 Electrical Characteristics for 1.8-V Supply

 V_{CC} = 1.65 V to 1.95 V, T_A = -40°C to 85°C (unless otherwise noted)⁽¹⁾

| PAR | AMETER | TEST COND | ITIONS | T _A | V _{cc} | MIN | TYP | MAX | UNIT | |
|---|--|---|--|----------------|------------------------|--------|------|-----------------|------------|---|
| ANALOG SWI | тсн | | | | | | | · | | |
| V _{COM} , V _{NO} , V _{NC} | Analog signal range | | | | | 0 | | V _{CC} | V | |
| D | Peak ON | $0 \le (V_{NO} \text{ or } V_{NC}) \le V_{CC},$ | Switch ON, | 25°C | 1.65 V | | 5 | | Ω | |
| R _{peak} | resistance | $I_{COM} = -2 \text{ mA},$ | See Figure 14 | Full | 1.05 V | | | 15 | Ω | |
| R _{on} | ON-state | V_{NO} or V_{NC} = 1.5 V, | Switch ON, | 25°C | 1.65 V | | 2 | 2.5 | Ω | |
| von | resistance | $I_{COM} = -2 \text{ mA},$ | See Figure 14 | Full | 1.00 V | | | 3.5 | 32 | |
| | ON-state | | | 25°C | _ | | 0.15 | 0.4 | | |
| ΔR _{on} | resistance match between channels | $\label{eq:VNO} \begin{array}{l} V_{NO} \mbox{ or } V_{NC} = 0.6 \mbox{ V}, \mbox{ 1.5 V}, \\ I_{COM} = -2 \mbox{ mA}, \end{array}$ | Switch ON, See Figure 14 | Full | 1.65 V | | | 0.4 | Ω | |
| 5 | ON-state | $\label{eq:VNC} \begin{array}{l} 0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{CC}, \\ I_{COM} = -2 \text{ mA}, \end{array}$ | Switch ON, See Figure 14 | 25°C | 4.05.14 | | 5 | | • | |
| R _{on(flat)} | resistance flatness | flatness V_{NO} or $V_{NC} = 0.6 V$ | | | 25°C | 1.65 V | | 4.5 | | Ω |
| | | $I_{COM} = -2 \text{ mA},$ | See Figure 14 | Full | | | | | | |
| | | V_{NC} or $V_{NO} = 0.3 V$, | | 25°C | | -20 | 2 | 20 | | |
| I _{NO(OFF)} , I _{NC(OFF)} | NC, NO OFF leakage | | Switch OFF, See Figure 15 | Full | 1.65 V | -50 | | 50 | nA | |
| | current | V_{NC} or $V_{NO} = 0$ to | Switch OFF, | 25°C | | -1 | 0.1 | 1 | | |
| INC(PWROFF), INO(PWROFF) | | 1.95 V, V _{COM} = 1.95 V to 0, | See Figure 15 | Full | 0 V | -5 | | 5 | μA | |
| | | $V_{\rm NC}$ or $V_{\rm NO} = 0.3$ V, | | 25°C | | -5 | 2 | 5 | | |
| I _{NO(ON)} , I _{NC(ON)} | NC, NO ON leakage current | $V_{COM} = Open,$ or V_{NC} or $V_{NO} = 1.65 V,$ $V_{COM} = Open,$ | Switch ON, See Figure 16 | Full | 1.95 V | -20 | | 20 | nA | |
| | COM | | | 25°C | | -1 | 0.1 | 1 | | |
| I _{COM(PWROFF)} | OFF leakage current | $\label{eq:VNC} \begin{array}{l} V_{\text{NC}} \text{ or } V_{\text{NO}} = 1.95 \text{ V to } 0, \\ V_{\text{COM}} = 0 \text{ to } 1.95 \text{ V}, \end{array}$ | Switch OFF, See Figure 15 | Full | 0 V | -5 | - | 5 | μA | |
| | 0014 | V_{NC} or V_{NO} = Open, | | 25°C | | -10 | 2 | 10 | | |
| I _{COM(ON)} | COM ON leakage current | $\label{eq:comparameters} \begin{array}{l} V_{COM} = 0.3 \ V, \\ \text{or} \\ V_{NC} \ \text{or} \ V_{NO} = \text{Open}, \\ V_{COM} = 1.65 \ V, \end{array}$ | Switch ON, See Figure 16 | Full | 1.95 V | -20 | | 20 | nA | |
| DIGITAL CON | TROL INPUTS (IN | 1, IN2) | | | 1. L | | | | | |
| V _{IH} | Input logic high | | | Full | | 1.5 | | 5.5 | V | |
| V _{IL} | Input logic low | | | Full | | 0 | | 0.6 | V | |
| | Input leakage | | | 25°C | 1.05.1/ | -2 | | 2 | r ^ | |
| I _{IH} , I _{IL} | current | $V_{IN} = 5.5 V \text{ or } 0$ | | Full | 1.95 V | -20 | | 20 | nA | |
| DYNAMIC | | | | | | | | | | |
| | | | | 25°C | 1.8 V | 10 | 27.5 | 48.5 | | |
| t _{ON} | Turnon time | | C _L = 35 pF, See Figure 18 | Full | 1.65 V to 1.95 V | 10 | | 55 | ns | |
| | | | | 25°C | 1.8 V | 2 | 6.5 | 11 | | |
| t _{OFF} | Turnoff time | | C _L = 35 pF, See Figure 18 | Full | 1.65 V to 1.95 V | 2 | | 12 | ns | |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

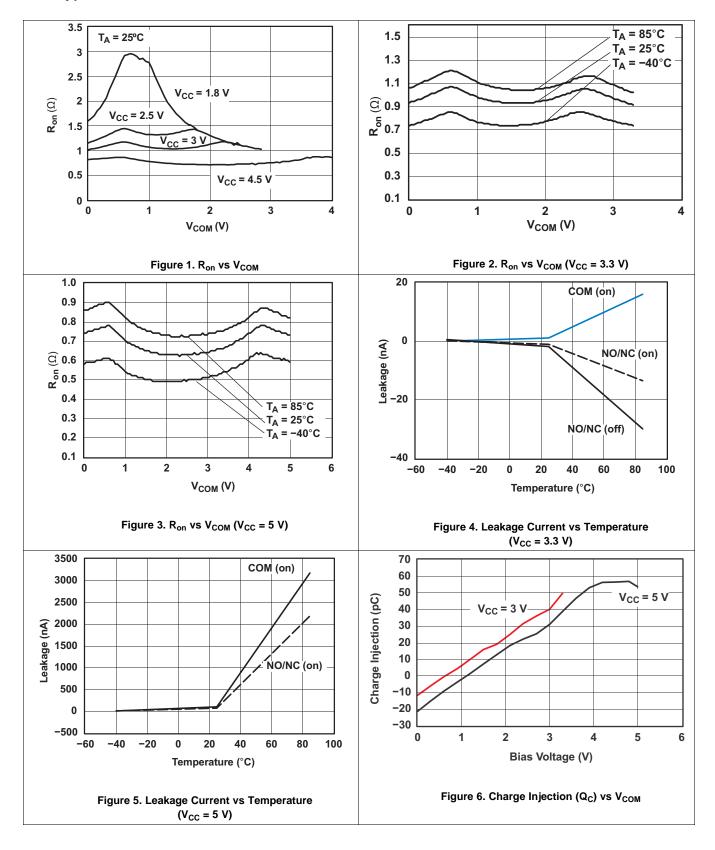
Electrical Characteristics for 1.8-V Supply (continued)

| $V_{00} = 1.65 \text{ V to } 1.95 \text{ V} \text{ T}$ | $A = -40^{\circ}$ C to 85°C (unless | otherwise noted) ⁽¹⁾ |
|--|-------------------------------------|---------------------------------|
| $v_{\rm CC} = 1.00 \ v$ to 1.00 v, 1 | A = +0.010000 (unicoo | |

| PA | RAMETER | TEST CON | NDITIONS | TA | V _{cc} | MIN | TYP | MAX | UNIT |
|--|------------------------------|--|--|------|------------------------|-----|-------|-----|------|
| | | | | 25°C | 1.8 V | 1 | 18 | 50 | |
| t _{BBM} | Break-before- make time | $\label{eq:VNC} \begin{split} V_{NC} &= V_{NO} = V_{CC}, \\ R_L &= 50 \ \Omega, \end{split}$ | C _L = 35 pF, See Figure 19 | Full | 1.65 V to 1.95 V | 1 | | 55 | ns |
| Q _C | Charge injection | $V_{GEN} = 0,$ $R_{GEN} = 0,$ | C _L = 1 nF, See Figure 23 | 25°C | 1.8 V | | 2 | | рС |
| C _{NC(OFF)} , C _{NO(OFF)} | NC, NO OFF capacitance | V_{NC} or $V_{NO} = V_{CC}$ or GND, Switch OFF, | See Figure 17 | 25°C | 1.8 V | | 18.5 | | pF |
| C _{NC(ON)} , C _{NO(ON)} | NC, NO ON capacitance | V_{NC} or $V_{NO} = V_{CC}$ or GND, Switch ON, | See Figure 17 | 25°C | 1.8 V | | 56.5 | | pF |
| C _{COM(ON)} | COM ON capacitance | $V_{COM} = V_{CC}$ or GND, Switch ON, | See Figure 17 | 25°C | 1.8 V | | 56.5 | | pF |
| CI | Digital input capacitance | $V_{IN} = V_{CC}$ or GND, | See Figure 17 | 25°C | 1.8 V | | 2 | | pF |
| BW | Bandwidth | $R_L = 50 \Omega$, Switch ON, | See Figure 20 | 25°C | 1.8 V | | 105 | | MHz |
| O _{ISO} | OFF isolation | $ \begin{array}{l} R_{L} = 50 \ \Omega, \\ f = 1 \ MHz, \end{array} $ | Switch OFF, See Figure 21 | 25°C | 1.8 V | | -64 | | dB |
| X _{TALK} | Crosstalk | $ \begin{array}{l} R_{L} = 50 \ \Omega, \\ f = 1 \ MHz, \end{array} $ | Switch ON, See Figure 22 | 25°C | 1.8 V | | -64 | | dB |
| THD | Total harmonic distortion | $R_L = 600 \Omega,$ $C_L = 50 pF,$ | f = 20 Hz to 20 kHz, See Figure 24 | 25°C | 1.8 V | | 0.06% | | |
| SUPPLY | | | | | | | | | |
| | Positive supply | | Switch ON or OFF | 25°C | 1.95 V | | 10 | 25 | nA |
| I _{CC} current | | $V_{IN} = V_{CC}$ or GND, Switch ON or OFF | | Full | 1.95 V | | | ПА | |



6.9 Typical Characteristics

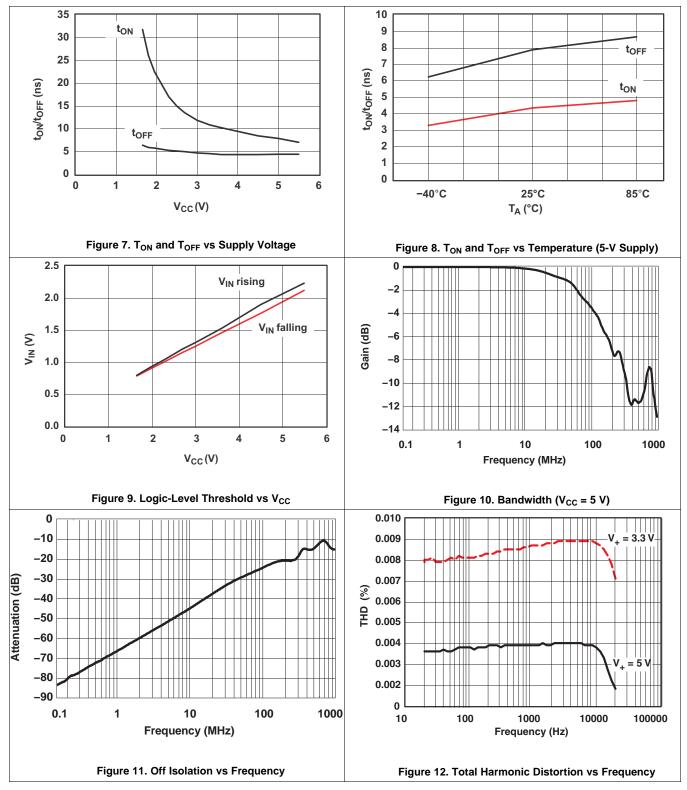


SCDS201H-AUGUST 2005-REVISED FEBRUARY 2015



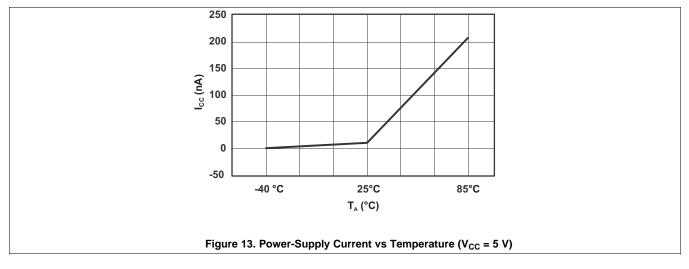
www.ti.com

Typical Characteristics (continued)





Typical Characteristics (continued)





7 Parameter Measurement Information

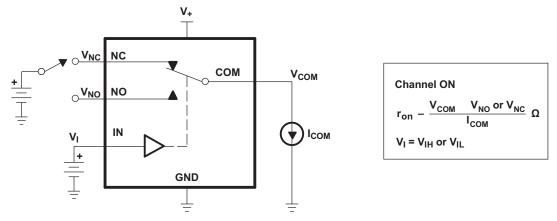


Figure 14. ON-State Resistance (Ron)

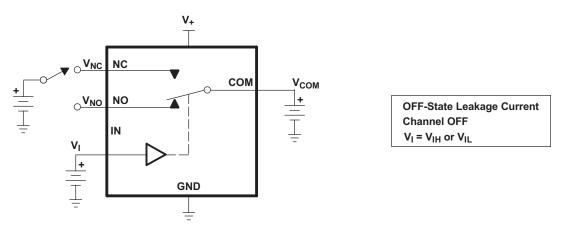
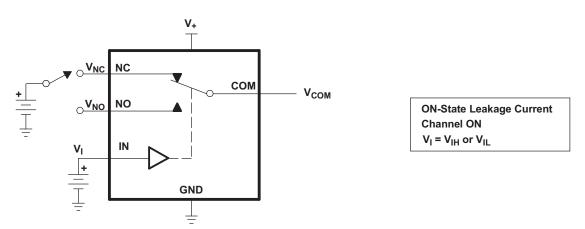
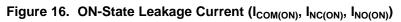


Figure 15. OFF-State Leakage Current (I_{NC(OFF)}, I_{NC(PWROFF)}, I_{NO(OFF)}, I_{NO(OFF)}, I_{COM(PWROFF)})







Parameter Measurement Information (continued)

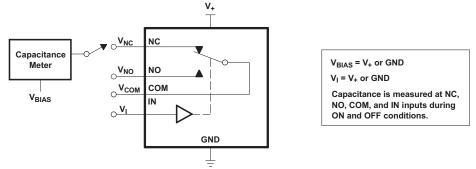
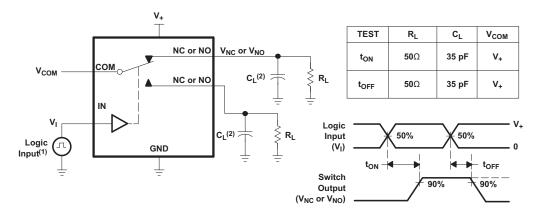


Figure 17. Capacitance (C_I, C_{COM(ON)}, C_{NC(OFF)}, C_{NO(OFF)}, C_{NC(ON)}, C_{NO(ON)})

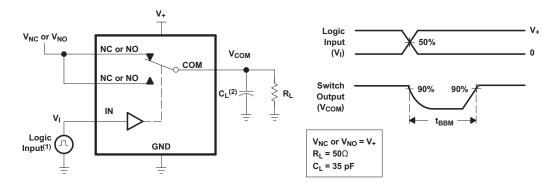


1. All input pulses are supplied by generators having the following characteristics:

PRR 3 10 MHz, $Z_O = 50 \ \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.

2. C_{L} includes probe and jig capacitance.

Figure 18. Turnon (T_{ON}) and Turnoff Time (T_{OFF})



1. All input pulses are supplied by generators having the following characteristics:

PRR 3 10 MHz, Z_{O} = 50 Ω , t_{r} < 5 ns, t_{f} < 5 ns.

2. C_L includes probe and jig capacitance.

Figure 19. Break-Before-Make Time (T_{BBM})

Parameter Measurement Information (continued) V+ **Network Analyzer** 50 Ω V_{NC} NC Channel ON: NC to COM $V_I = V_+ \text{ or } GND$ сом V_{COM} Source NO Signal Network Analyzer Setup IN Source Power = 0 dBm ٧ı 50 Ω ≶ (632-mV P-P at 50-Ω load) GND -DC Bias = 350 mV Ŧ

Figure 20. Bandwidth (Bw)

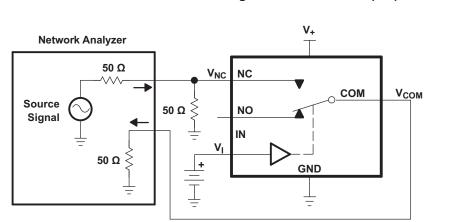
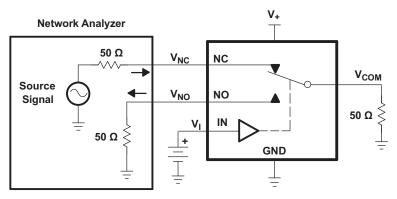
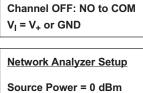


Figure 21. Off Isolation (O_{ISO})







Channel ON: NC to COM

(632-mV P-P at 50-Ω load) DC Bias = 350 mV

www.ti.com

ISTRUMENTS

EXAS

<u>Network Analyzer Setup</u> Source Power = 0 dBm (632-mV P-P at 50-Ω load) DC Bias = 350 mV

Channel OFF: NC to COM

 $V_I = V_+ \text{ or } GND$

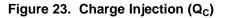


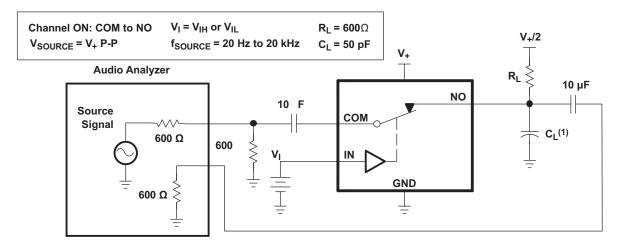
Parameter Measurement Information (continued) V+ Logic Input OFF ON OFF (V_{I)} VIL R_{GEN} NC or NO ★. сом V_{COM} DV_{COM} V_{COM} NC or NO V_{GEN} C CL⁽²⁾ V_{GEN} = 0 to V₊ VI IN $R_{GEN} = 0$ C_L = 1 nF Logic GND $Q_C = C_{L\Psi} \times \Delta V_{COM}$ Input⁽¹⁾ $V_I = V_{IH} \text{ or } V_{IL}$

1. All input pulses are supplied by generators having the following characteristics:

PRR 3 10 MHz, $Z_O = 50 \ \Omega$, $t_r < 5 \ \text{ns}$, $t_f < 5 \ \text{ns}$.

2. C_L includes probe and jig capacitance.





1. C_L includes probe and jig capacitance.

Figure 24. Total Harmonic Distortion (THD)

NSTRUMENTS

Texas

Parameter Measurement Information (continued) Table 1. Parameter Description

| SYMBOL | DESCRIPTION |
|-----------------------------------|--|
| V _{COM} | Voltage at COM |
| V _{NC} | Voltage at NC |
| V _{NO} | Voltage at NO |
| R _{on} | Resistance between COM and NC or COM and NO ports when the channel is ON |
| R _{peak} | Peak on-state resistance over a specified voltage range |
| ΔR _{on} | Difference of Ron between channels in a specific device |
| R _{on(flat)} | Difference between the maximum and minimum value of Ron in a channel over the specified range of conditions |
| I _{NC(OFF)} | Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state under worst- case input and output conditions |
| I _{NC(PWROFF)} | Leakage current measured at the NC port during the power-down condition, V _{CC} = 0 |
| I _{NO(OFF)} | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state under worst- case input and output conditions |
| INO(PWROFF) | Leakage current measured at the NO port during the power-down condition, V _{CC} = 0 |
| I _{NC(ON)} | Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) open |
| I _{NO(ON)} | Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open |
| I _{COM(ON)} | Leakage current measured at the COM port, with the corresponding channel (COM to NO or COM to NC) in the ON state and the output (NC or NO) open |
| ICOM(PWROFF) | Leakage current measured at the COM port during the power-down condition, $V_{CC} = 0$ |
| V _{IH} | Minimum input voltage for logic high for the control input (IN) |
| V _{IL} | Maximum input voltage for logic low for the control input (IN) |
| V _{IN} | Voltage at the control input (IN) |
| I _{IH} , I _{IL} | Leakage current measured at the control input (IN) |
| t _{ON} | Turnon time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM, NC, or NO) signal when the switch is turning ON. |
| t _{OFF} | Turnoff time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM, NC, or NO) signal when the switch is turning OFF. |
| t _{BBM} | Break-before-make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO) when the control signal changes state. |
| Q _C | Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_c = C_L \times \Delta V_{COM}$. C_L is the load capacitance and ΔV_{COM} is the change in analog output voltage. |
| C _{NC(OFF)} | Capacitance at the NC port when the corresponding channel (NC to COM) is OFF |
| C _{NO(OFF)} | Capacitance at the NO port when the corresponding channel (NO to COM) is OFF |
| C _{NC(ON)} | Capacitance at the NC port when the corresponding channel (NC to COM) is ON |
| C _{NO(ON)} | Capacitance at the NO port when the corresponding channel (NO to COM) is ON |
| C _{COM(ON)} | Capacitance at the COM port when the corresponding channel (COM to NC or COM to NO) is ON |
| CI | Capacitance of control input (IN) |
| O _{ISO} | OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the OFF state. |
| X _{TALK} | Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC to NO or NO to NC). This is measured in a specific frequency and in dB. |
| BW | Bandwidth of the switch. This is the frequency in which the gain of an ON channel is -3 dB below the DC gain. |
| THD | Total harmonic distortion is defined as the ratio of the root mean square (RMS) value of the second, third, and higher harmonics to the magnitude of fundamental harmonic. |
| I _{CC} | Static power-supply current with the control (IN) pin at V_{CC} or GND |

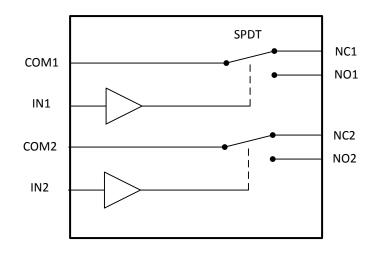


8 Detailed Description

8.1 Overview

The TS5A23159 is a bidirectional 2-channel single-pole double-throw (SPDT) switch that is designed to operate from 1.65 V to 5.5 V. The device offers low ON-state resistance and excellent ON-state resistance matching with the break-before-make feature which prevents signal distortion during the transferring of a signal from one channel to another. The device has an excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for a wide variety of portable applications including cell phones, audio devices, and instrumentation.

8.2 Functional Block Diagram



8.3 Feature Description

The TS5A23159 is a bidirectional device that has two single-pole, double-throw switches. The two channels of the switch are contorled independantly by two digital signals; one digital control for each single-pole, double-throw switch.

8.4 Device Functional Modes

| IN | NC to COM, COM to NC | NO to COM, COM to NO |
|----|-------------------------|-------------------------|
| L | ON | OFF |
| Н | OFF | ON |

Table 2. Function Table



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The switches are bidirectional, so the NO, NC, and COM pins can be used as either inputs or outputs.

9.2 Typical Application

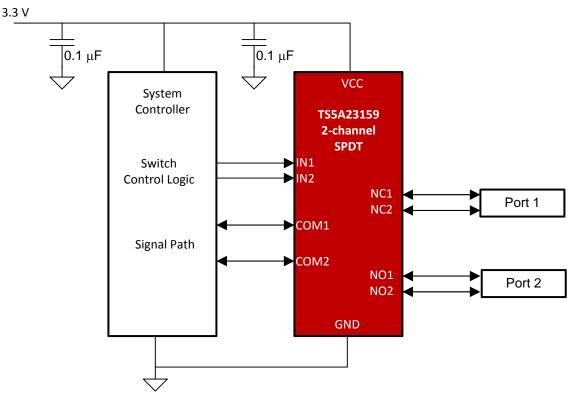


Figure 25. Typical Application Diagram

9.2.1 Design Requirements

Ensure that all of the signals passing through the switch are within the specified ranges in the recommended operating conditions to ensure proper performance.

9.2.2 Detailed Design Procedure

The TS5A23159 can be properly operated without any external components. However, TI recommends connecting unused pins to ground through a $50-\Omega$ resistor to prevent signal reflections back into the device. TI also recommends that the digital control pins (INX) be pulled up to VCC or down to GND to avoid undesired switch positions that could result from the floating pin.



Typical Application (continued)

9.2.3 Application Curve

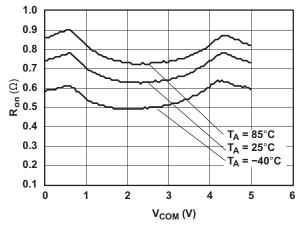


Figure 26. $R_{on} vs V_{COM} (V_{CC} = 5 V)$

10 Power Supply Recommendations

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the device. Always sequence VCC on first, followed by NO, NC, or COM. Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the VCC supply to other components. A 0.1- μ F capacitor, connected from VCC to GND, is adequate for most applications.

TS5A23159 SCDS201H-AUGUST 2005-REVISED FEBRUARY 2015

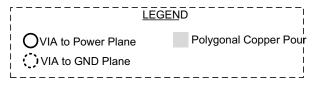


11 Layout

11.1 Layout Guidelines

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

11.2 Layout Example



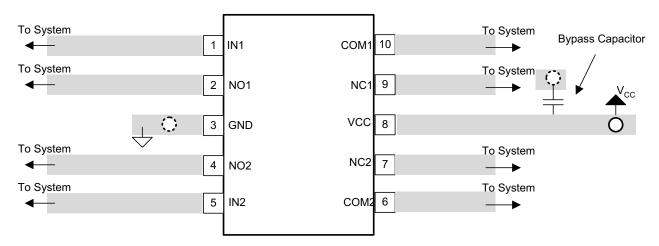


Figure 27. Layout Recommendation



12 Device and Documentation Support

12.1 Trademarks

All trademarks are the property of their respective owners.

12.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|-------------------------------|--------------------|--------------|--------------------------|---------|
| | | | | | | | (6) | | | | |
| TS5A23159DGSR | ACTIVE | VSSOP | DGS | 10 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | (JEQ, JER) | Samples |
| TS5A23159DGST | OBSOLETE | VSSOP | DGS | 10 | | TBD | Call TI | Call TI | -40 to 85 | JER | |
| TS5A23159RSER | ACTIVE | UQFN | RSE | 10 | 3000 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 85 | (JE7, JEO, JER, JE V) | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



Texas

STRUMENTS

www.ti.com

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| TS5A23159DGSR | VSSOP | DGS | 10 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TS5A23159RSER | UQFN | RSE | 10 | 3000 | 180.0 | 9.5 | 1.7 | 2.2 | 0.75 | 4.0 | 8.0 | Q1 |
| TS5A23159RSER | UQFN | RSE | 10 | 3000 | 180.0 | 9.5 | 1.7 | 2.3 | 0.75 | 4.0 | 8.0 | Q1 |



PACKAGE MATERIALS INFORMATION

14-Dec-2024



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TS5A23159DGSR | VSSOP | DGS | 10 | 2500 | 358.0 | 335.0 | 35.0 |
| TS5A23159RSER | UQFN | RSE | 10 | 3000 | 189.0 | 185.0 | 36.0 |
| TS5A23159RSER | UQFN | RSE | 10 | 3000 | 184.0 | 184.0 | 19.0 |

DGS0010A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187, variation BA.



DGS0010A

EXAMPLE BOARD LAYOUT

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DGS0010A

EXAMPLE STENCIL DESIGN

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

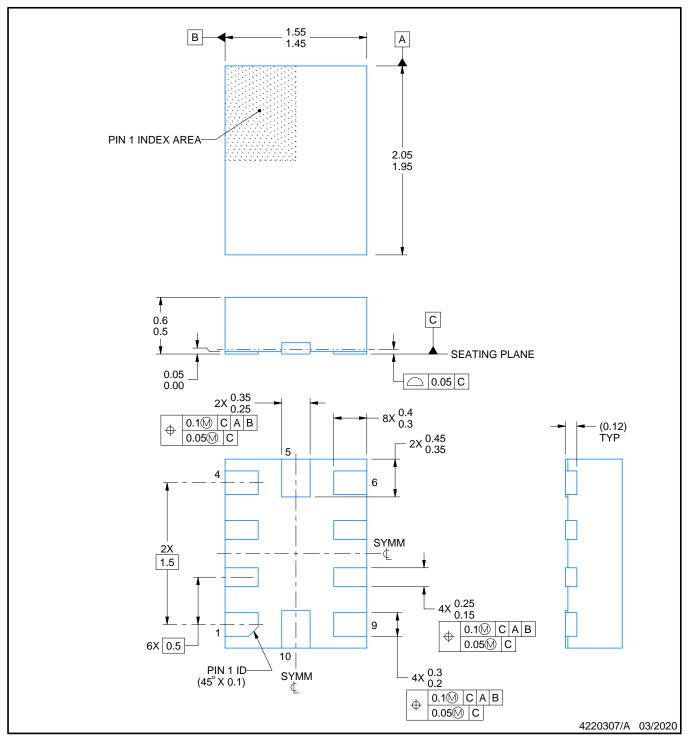
RSE0010A



PACKAGE OUTLINE

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

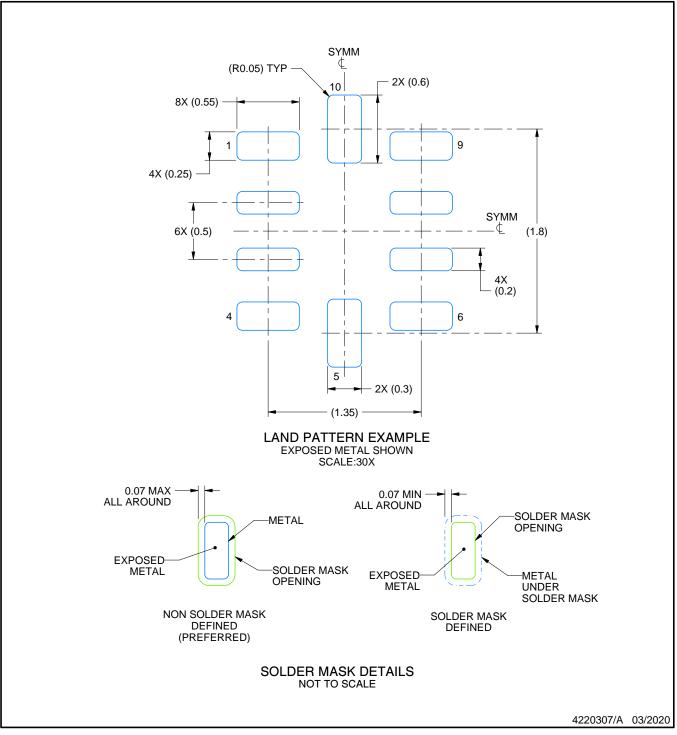


RSE0010A

EXAMPLE BOARD LAYOUT

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

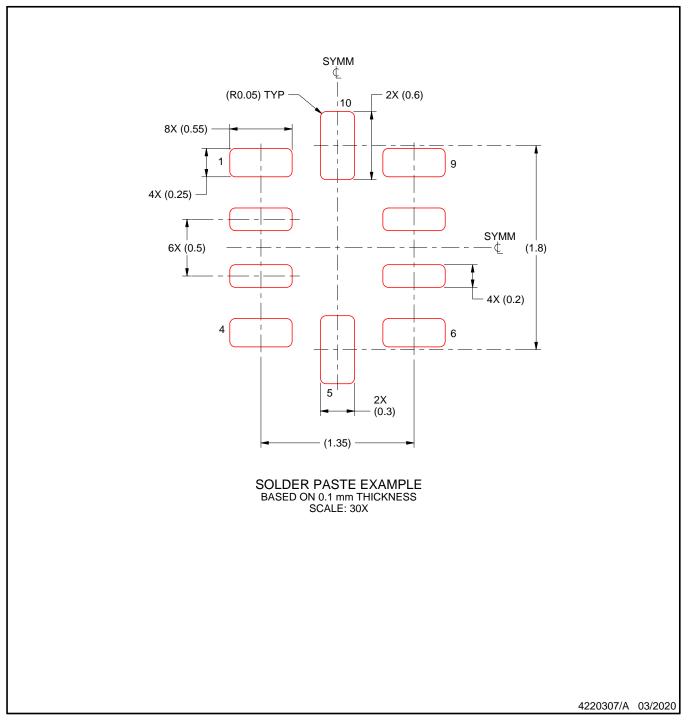


RSE0010A

EXAMPLE STENCIL DESIGN

UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated